

SURFACE MOUNT NPN SILICON TRANSISTOR



V_{CE}=10V, I_C=150mA

V_{CE}=10V, I_C=500mA

V_{CF}=10V, I_C=50mA, f=1.0MHz

 V_{CE} =10V, I_C=100µA, R_S=1.0kΩ,

V_{CB}=10V, I_E=0, f=1.0MHz

 V_{EB} =0.5V, I_C=0, f=1.0MHz

V_{CE}=10V, I_C=1.0A

f=1.0kHz

hFE

hFE

h_{FE}

Cob

C_{ib} NF

fT

Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXT3019 type is an NPN silicon transistor manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for high current general purpose amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (TA=25°C)		SYMBOL		UNITS		
Collector-Base Voltage		V _{CBO}	140	V		
Collector-Emitter Voltage		V _{CEO}	80	V		
Emitter-Base Voltage		V _{EBO}	7.0	V		
Continuous Collector Current		۱ _C	1.0	А		
Peak Collector Current		ICM	1.5	А		
Power Dissipation		PD	1.2	W		
Operating and Storage Junction Temperature		T _{J,} T _{stg}	-65 to +175	°C		
Thermal Resistance		ΘJA	125	°C/W		
ELECTRICAL CHARACTERISTICS: (TA=25°C unless otherwise noted)						
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS		
ICBO	V _{CB} =90V		10	nA		
IEBO	V _{EB} =5.0V		10	nA		
BVCBO	Ι _C =100μΑ	140		V		
BV _{CEO}	I _C =30mA	80		V		
BVEBO	I _E =100μA	7.0		V		
V _{CE(SAT)}	I _C =150mA, I _B =15mA		0.2	V		
V _{CE(SAT)}	I _C =500mA, I _B =50mA		0.5	V		
VBE(SAT)	I _C =150mA, I _B =15mA		1.1	V		
h _{FE}	V _{CE} =10V, I _C =0.1mA	50				
h _{FE}	V _{CE} =10V, I _C =10mA	90				

100

50

15

100

300

12

60

4.0

MHz

pF

pF

dB R7 (23-February 2010)



CXT3019

SURFACE MOUNT NPN SILICON TRANSISTOR

D -Е ΒЭ T G t Ĥ 2 3 1 c J -ĸ _ Т R4 Μ (Bottom View)

SOT-89 CASE - MECHANICAL OUTLINE

- 1) Emitter
 2) Collector
 3) Base

MARKING: FULL PART NUMBER

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
А	0.055	0.067	1.40	1.70			
В	4°		4°				
С	0.014	0.018	0.35	0.46			
D	0.173	0.185	4.40	4.70			
E	0.064	0.074	1.62	1.87			
F	0.146	0.177	3.70	4.50			
G	0.090	0.106	2.29	2.70			
Н	0.028	0.051	0.70	1.30			
J	0.014	0.019	0.36	0.48			
K	0.017	0.023	0.44	0.58			
L	0.059		1.50				
М	0.118		3.00				
SOT-89 (REV/· R4)							

SOT-89 (REV: R4)

R7 (23-February 2010)

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

Special wafer diffusions

· Custom product packing

- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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